

# 80MHz, 25V/ $\mu$ s Low Power Rail-to-Rail Input and Output Precision Op Amp

October 2001

## FEATURES

- Gain Bandwidth Product: 80MHz
- Input Common Mode Range Includes Both Rails
- Output Swings Rail-to-Rail
- Low Quiescent Current: 2mA Max
- Input Offset Voltage: 350 $\mu$ V Max
- Input Bias Current: 250nA Max
- Large Output Current: 50mA Typ
- Low Voltage Noise: 8nV/ $\sqrt{\text{Hz}}$
- Slew Rate: 25V/ $\mu$ s
- Common Mode Rejection: 105dB Typ
- Power Supply Rejection: 97dB Typ
- Open-Loop Gain: 85V/mV Typ
- Available in the 8-Pin SO and 5-Pin Low Profile (1mm) ThinSOT™ Packages
- Operating Temperature Range: -40°C to 85°C

## APPLICATIONS

- Low Voltage, High Frequency Signal Processing
- Driving A/D Converters
- Rail-to-Rail Buffer Amplifiers
- Active Filters
- Video Line Driver

## DESCRIPTION

The LT<sup>®</sup>1800 is a low power, high speed rail-to-rail input and output operational amplifier with excellent DC performance. The LT1800 features reduced supply current, lower input offset voltage, lower input bias current and higher DC gain than other devices with comparable bandwidth.

The LT1800 has an input range that includes both supply rails and an output that swings within 20mV of either supply rail to maximize the signal dynamic range in low supply applications.

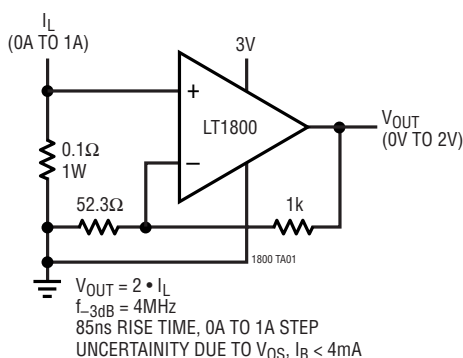
The LT1800 maintains its performance for supplies from 2.3V to 12.6V and is specified at 3V, 5V and  $\pm$ 5V supplies. The inputs can be driven beyond the supplies without damage or phase reversal of the output.

The LT1800 is available in the 8-pin SO package with the standard op amp pinout and in the 5-pin SOT-23 package. The LT1800 can be used as a plug-in replacement for many op amps to improve input/output range and performance.

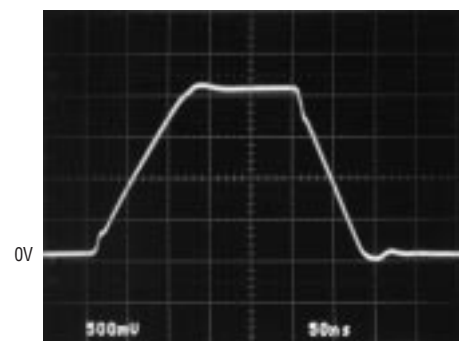
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## TYPICAL APPLICATION

### Fast 1A Current Sense



### Large-Signal Response



$V_S = 3\text{V}$ , 0V  
 $A_V = 1$   
 $R_L = 1\text{k}$

1800 TA02

## ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage ( $V_S^-$ to $V_S^+$ ) .....	12.6V	Specified Temperature Range (Note 5) ...	-40°C to 85°C
Input Voltage (Note 2) .....	$\pm V_S$	Junction Temperature .....	150°C
Input Current (Note 2) .....	$\pm 10\text{mA}$	Storage Temperature Range .....	-65°C to 150°C
Output Short-Circuit Duration (Note 3) .....	Indefinite	Lead Temperature (Soldering, 10 sec) .....	300°C
Operating Temperature Range (Note 4) ..	-40°C to 85°C		

## PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER		ORDER PART NUMBER
	LT1800CS8 LT1800IS8		LT1800CS5 LT1800IS5
	S8 PART MARKING		S5 PART MARKING
	1800 1800I		LTRN LTRP

Consult LTC Marketing for parts specified with wider operating temperature ranges.

## ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $0\text{V}$ ;  $V_S = 3\text{V}$ ,  $0\text{V}$ ;  $V_{CM} = V_{OUT} = \text{half supply}$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{OS}$	Input Offset Voltage	$V_{CM} = 0\text{V}$		75	350	$\mu\text{V}$
		$V_{CM} = 0\text{V}$ (SOT-23)		300	750	$\mu\text{V}$
		$V_{CM} = V_S$		0.5	3	mV
		$V_{CM} = V_S$ (SOT-23)		0.7	3.5	mV
$\Delta V_{OS}$	Input Offset Shift	$V_{CM} = 0\text{V}$ to $V_S - 1.5\text{V}$		20	180	$\mu\text{V}$
$I_B$	Input Bias Current	$V_{CM} = 1\text{V}$		25	250	nA
		$V_{CM} = V_S$		500	1500	nA
$I_{OS}$	Input Offset Current	$V_{CM} = 1\text{V}$		25	200	nA
		$V_{CM} = V_S$		25	200	nA
	Input Noise Voltage	0.1Hz to 10Hz		0.750		$\mu\text{V}_{p-p}$
$e_n$	Input Noise Voltage Density	$f = 10\text{kHz}$		8		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input Noise Current Density	$f = 10\text{kHz}$		1.4		$\text{pA}/\sqrt{\text{Hz}}$
$C_{IN}$	Input Capacitance			2		pF
$A_{VOL}$	Large-Signal Voltage Gain	$V_S = 5\text{V}$ , $V_O = 0.5\text{V}$ to $4.5\text{V}$ , $R_L = 1\text{k}$ at $V_S/2$	35	85		V/mV
		$V_S = 5\text{V}$ , $V_O = 1\text{V}$ to $4\text{V}$ , $R_L = 100\Omega$ at $V_S/2$	3.5	8		V/mV
		$V_S = 3\text{V}$ , $V_O = 0.5\text{V}$ to $2.5\text{V}$ , $R_L = 1\text{k}$ at $V_S/2$	30	85		V/mV
CMRR	Common Mode Rejection Ratio	$V_S = 5\text{V}$ , $V_{CM} = 0\text{V}$ to $3.5\text{V}$	85	105		dB
		$V_S = 3\text{V}$ , $V_{CM} = 0\text{V}$ to $1.5\text{V}$	78	97		dB
	Input Common Mode Range		0		$V_S$	V
PSRR	Power Supply Rejection Ratio	$V_S = 2.5\text{V}$ to $10\text{V}$ , $V_{CM} = 0\text{V}$	80	97		dB
		Minimum Supply Voltage (Note 6)		2.3	2.5	

## ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}, 0\text{V}$ ;  $V_S = 3\text{V}, 0\text{V}$ ;  $V_{CM} = V_{OUT} = \text{half supply}$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{OL}$	Output Voltage Swing Low (Note 7)	No Load		12	50	mV
		$I_{SINK} = 5\text{mA}$		80	160	mV
		$I_{SINK} = 20\text{mA}$		225	450	mV
$V_{OH}$	Output Voltage Swing High (Note 7)	No Load		16	60	mV
		$I_{SOURCE} = 5\text{mA}$		120	250	mV
		$I_{SOURCE} = 20\text{mA}$		450	750	mV
$I_{SC}$	Short-Circuit Current	$V_S = 5\text{V}$	20	45		mA
		$V_S = 3\text{V}$	20	40		mA
$I_S$	Supply Current per Amplifier			1.6	2	mA
GBW	Gain Bandwidth Product	Frequency = 2MHz	40	80		MHz
SR	Slew Rate	$V_S = 5\text{V}$ , $A_V = -1$ , $R_L = 1\text{k}$ , $V_O = 4\text{V}$	13	25		V/ $\mu\text{s}$
FPBW	Full Power Bandwidth	$V_S = 5\text{V}$ , $V_{OUT} = 4V_{P-P}$		2		MHz
HD	Harmonic Distortion	$V_S = 5\text{V}$ , $A_V = 1$ , $R_L = 1\text{k}$ , $V_O = 2V_{P-P}$ , $f_C = 1\text{MHz}$		-75		dBc
$t_S$	Settling Time	0.01%, $V_S = 5\text{V}$ , $V_{STEP} = 2\text{V}$ , $A_V = 1$ , $R_L = 1\text{k}$		250		ns
$\Delta G$	Differential Gain (NTSC)	$V_S = 5\text{V}$ , $A_V = +2$ , $R_L = 150\Omega$		0.35		%
$\Delta\theta$	Differential Phase (NTSC)	$V_S = 5\text{V}$ , $A_V = +2$ , $R_L = 150\Omega$		0.4		Deg

The ● denotes the specifications which apply over the temperature range of  $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ .  $V_S = 5\text{V}, 0\text{V}$ ;  $V_S = 3\text{V}, 0\text{V}$ ;  $V_{CM} = V_{OUT} = \text{half supply}$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{OS}$	Input Offset Voltage	$V_{CM} = 0\text{V}$	●	125	500	$\mu\text{V}$
		$V_{CM} = 0\text{V}$ (SOT-23)	●	300	1250	$\mu\text{V}$
		$V_{CM} = V_S$	●	0.6	3.5	mV
		$V_{CM} = V_S$ (SOT-23)	●	0.7	3.75	mV
$\Delta V_{OS}$	Input Offset Shift	$V_{CM} = 0\text{V}$ to $V_S - 1.5\text{V}$	●	30	275	$\mu\text{V}$
$V_{OS\ TC}$	Input Offset Voltage Drift (Note 8)	$V_{CM} = 0\text{V}$	●	1.5		$\mu\text{V}/^\circ\text{C}$
		$V_{CM} = V_S$	●	1.5		$\mu\text{V}/^\circ\text{C}$
$I_B$	Input Bias Current	$V_{CM} = 1\text{V}$	●	50	300	nA
		$V_{CM} = V_S - 0.2\text{V}$	●	550	1750	nA
$I_{OS}$	Input Offset Current	$V_{CM} = 1\text{V}$	●	25	250	nA
		$V_{CM} = V_S - 0.2\text{V}$	●	25	250	nA
$A_{VOL}$	Large-Signal Voltage Gain	$V_S = 5\text{V}$ , $V_O = 0.5\text{V}$ to $4.5\text{V}$ , $R_L = 1\text{k}$ at $V_S/2$	●	30	75	V/mV
		$V_S = 5\text{V}$ , $V_O = 1\text{V}$ to $4\text{V}$ , $R_L = 100\Omega$ at $V_S/2$	●	3	6	V/mV
		$V_S = 3\text{V}$ , $V_O = 0.5\text{V}$ to $2.5\text{V}$ , $R_L = 1\text{k}$ at $V_S/2$	●	25	75	V/mV
CMRR	Common Mode Rejection Ratio	$V_S = 5\text{V}$ , $V_{CM} = 0\text{V}$ to $3.5\text{V}$	●	82	101	dB
		$V_S = 3\text{V}$ , $V_{CM} = 0\text{V}$ to $1.5\text{V}$	●	74	93	dB
	Input Common Mode Range		●	0	$V_S$	V
PSRR	Power Supply Rejection Ratio	$V_S = 2.5\text{V}$ to $10\text{V}$ , $V_{CM} = 0\text{V}$	●	74	91	dB
		Minimum Supply Voltage (Note 6)	●	2.3	2.5	V
$V_{OL}$	Output Voltage Swing Low (Note 7)	No Load	●	14	60	mV
		$I_{SINK} = 5\text{mA}$	●	100	200	mV
		$I_{SINK} = 20\text{mA}$	●	300	550	mV
$V_{OH}$	Output Voltage Swing High (Note 7)	No Load	●	25	80	mV
		$I_{SOURCE} = 5\text{mA}$	●	150	300	mV
		$I_{SOURCE} = 20\text{mA}$	●	600	950	mV
$I_{SC}$	Short-Circuit Current	$V_S = 5\text{V}$	●	20	40	mA
		$V_S = 3\text{V}$	●	20	30	mA
$I_S$	Supply Current per Amplifier		●	2	2.75	mA
GBW	Gain Bandwidth Product	Frequency = 2MHz	●	35	75	MHz
SR	Slew Rate	$V_S = 5\text{V}$ , $A_V = -1$ , $R_L = 1\text{k}$ , $V_O = 4V_{P-P}$	●	11	22	V/ $\mu\text{s}$

**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the temperature range of  $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ .  $V_S = 5\text{V}, 0\text{V}$ ;  $V_S = 3\text{V}, 0\text{V}$ ;  $V_{CM} = V_{OUT} = \text{half supply}$ , unless otherwise noted. (Note 5)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{OS}$	Input Offset Voltage	$V_{CM} = 0\text{V}$	●	175	700	$\mu\text{V}$
		$V_{CM} = 0\text{V}$ (SOT-23)	●	400	2000	$\mu\text{V}$
		$V_{CM} = V_S$	●	0.75	4	mV
		$V_{CM} = V_S$ (SOT-23)	●	0.9	4	mV
$\Delta V_{OS}$	Input Offset Shift	$V_{CM} = 0\text{V}$ to $V_S - 1.5\text{V}$	●	30	300	$\mu\text{V}$
$V_{OS\ TC}$	Input Offset Voltage Drift (Note 8)	$V_{CM} = 0\text{V}$	●	1.5		$\mu\text{V}/^{\circ}\text{C}$
		$V_{CM} = V_S$	●	1.5		$\mu\text{V}/^{\circ}\text{C}$
$I_B$	Input Bias Current	$V_{CM} = 1\text{V}$	●	50	400	nA
		$V_{CM} = V_S - 0.2\text{V}$	●	600	2000	nA
$I_{OS}$	Input Offset Current	$V_{CM} = 1\text{V}$	●	25	300	nA
		$V_{CM} = V_S - 0.2\text{V}$	●	25	300	nA
$A_{VOL}$	Large-Signal Voltage Gain	$V_S = 5\text{V}, V_O = 0.5\text{V}$ to $4.5\text{V}, R_L = 1\text{k}$ at $V_S/2$	●	25	65	V/mV
		$V_S = 5\text{V}, V_O = 1.5\text{V}$ to $3.5\text{V}, R_L = 100\Omega$ at $V_S/2$	●	2.5	6	V/mV
		$V_S = 3\text{V}, V_O = 0.5\text{V}$ to $2.5\text{V}, R_L = 1\text{k}$ at $V_S/2$	●	20	65	V/mV
CMRR	Common Mode Rejection Ratio	$V_S = 5\text{V}, V_{CM} = 0\text{V}$ to $3.5\text{V}$	●	81	101	dB
		$V_S = 3\text{V}, V_{CM} = 0\text{V}$ to $1.5\text{V}$	●	73	93	dB
	Input Common Mode Range		●	0	$V_S$	V
PSRR	Power Supply Rejection Ratio	$V_S = 2.5\text{V}$ to $10\text{V}, V_{CM} = 0\text{V}$	●	73	90	dB
		Minimum Supply Voltage (Note 6)	●	2.3	2.5	V
$V_{OL}$	Output Voltage Swing Low (Note 7)	No Load	●	15	70	mV
		$I_{SINK} = 5\text{mA}$	●	105	210	mV
		$I_{SINK} = 10\text{mA}$	●	170	400	mV
$V_{OH}$	Output Voltage Swing High (Note 7)	No Load	●	25	90	mV
		$I_{SOURCE} = 5\text{mA}$	●	150	350	mV
		$I_{SOURCE} = 10\text{mA}$	●	300	700	mV
$I_{SC}$	Short-Circuit Current	$V_S = 5\text{V}$	●	12.5	30	mA
		$V_S = 3\text{V}$	●	12.5	30	mA
$I_S$	Supply Current per Amplifier		●	2.1	3	mA
GBW	Gain Bandwidth Product	Frequency = $2\text{MHz}$	●	30	70	MHz
SR	Slew Rate	$V_S = 5\text{V}, A_V = -1, R_L = 1\text{k}, V_O = 4\text{V}$	●	10	18	V/ $\mu\text{s}$

## ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ ,  $V_S = \pm 5\text{V}$ ,  $V_{CM} = 0\text{V}$ ,  $V_{OUT} = 0\text{V}$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{OS}$	Input Offset Voltage	$V_{CM} = V_S^-$		150	500	$\mu\text{V}$
		$V_{CM} = V_S^-$ (SOT-23)		400	1000	$\mu\text{V}$
		$V_{CM} = V_S^+$		0.7	3.5	mV
		$V_{CM} = V_S^+$ (SOT-23)		1	4.5	mV
$\Delta V_{OS}$	Input Offset Shift	$V_{CM} = V_S^-$ to $V_S^+ - 1.5\text{V}$		30	475	$\mu\text{V}$
$I_B$	Input Bias Current	$V_{CM} = V_S^- + 1\text{V}$		25	350	nA
		$V_{CM} = V_S^+$		400	1500	nA
$I_{OS}$	Input Offset Current	$V_{CM} = V_S^- + 1\text{V}$		20	250	nA
		$V_{CM} = V_S^+$		20	250	nA
	Input Noise Voltage	0.1Hz to 10Hz		1		$\mu\text{V}_{P-P}$
$e_n$	Input Noise Voltage Density	$f = 10\text{kHz}$		8		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input Noise Current Density	$f = 10\text{kHz}$		1.2		$\text{pA}/\sqrt{\text{Hz}}$
$C_{IN}$	Input Capacitance	$f = 1000\text{kHz}$		2		pF
$A_{VOL}$	Large-Signal Voltage Gain	$V_O = -4\text{V}$ to $4\text{V}$ , $R_L = 1\text{k}$	25	70		V/mV
		$V_O = -2\text{V}$ to $2\text{V}$ , $R_L = 100\Omega$	2.5	7		V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = V_S^-$ to $3.5\text{V}$	85	109		dB
		Input Common Mode Range	$V_S^-$		$V_S^+$	V
PSRR	Power Supply Rejection Ratio	$V_S^+ = 2.5\text{V}$ to $10\text{V}$ , $V_S^- = 0\text{V}$	80	97		dB
$V_{OL}$	Output Voltage Swing Low (Note 7)	No Load		15	60	mV
		$I_{SINK} = 5\text{mA}$		85	170	mV
		$I_{SINK} = 20\text{mA}$		225	450	mV
$V_{OH}$	Output Voltage Swing High (Note 7)	No Load		17	70	mV
		$I_{SOURCE} = 5\text{mA}$		130	260	mV
		$I_{SOURCE} = 20\text{mA}$		450	750	mV
$I_{SC}$	Short-Circuit Current		30	50		mA
$I_S$	Supply Current per Amplifier			1.8	2.75	mA
GBW	Gain Bandwidth Product	Frequency = 2MHz		70		MHz
SR	Slew Rate	$A_V = -1$ , $R_L = 1\text{k}$ , $V_O = \pm 4\text{V}$ , Measured at $V_O = \pm 2\text{V}$		23		V/ $\mu\text{s}$
FPBW	Full Power Bandwidth	$V_O = 8\text{V}_{P-P}$		0.9		MHz
HD	Harmonic Distortion	$A_V = 1$ , $R_L = 1\text{k}$ , $V_O = 2\text{V}_{P-P}$ , $f_C = 1\text{MHz}$		-75		dBc
$t_S$	Settling Time	0.01%, $V_{STEP} = 5\text{V}$ , $A_V = 1\text{V}$ , $R_L = 1\text{k}$		300		ns
$\Delta G$	Differential Gain (NTSC)	$A_V = +2$ , $R_L = 150\Omega$		0.35		%
$\Delta\theta$	Differential Phase (NTSC)	$A_V = +2$ , $R_L = 150\Omega$		0.2		Deg

**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the temperature range of 0°C ≤ T<sub>A</sub> ≤ 70°C. V<sub>S</sub> = ±5V, V<sub>CM</sub> = 0V, V<sub>OUT</sub> = 0V, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V <sub>OS</sub>	Input Offset Voltage	V <sub>CM</sub> = V <sub>S</sub> <sup>-</sup>	●		200	800	μV
		V <sub>CM</sub> = V <sub>S</sub> <sup>-</sup> (SOT-23)	●		450	1500	μV
		V <sub>CM</sub> = V <sub>S</sub> <sup>+</sup>	●		0.75	4	mV
		V <sub>CM</sub> = V <sub>S</sub> <sup>+</sup> (SOT-23)	●		1	5	mV
ΔV <sub>OS</sub>	Input Offset Shift	V <sub>CM</sub> = V <sub>S</sub> <sup>-</sup> to V <sub>S</sub> <sup>+</sup> - 1.5V	●		45	675	μV
V <sub>OS</sub> TC	Input Offset Voltage Drift (Note 8)	V <sub>CM</sub> = V <sub>S</sub> <sup>-</sup>	●		1.5		μV/°C
		V <sub>CM</sub> = V <sub>S</sub> <sup>+</sup>	●		1.5		μV/°C
I <sub>B</sub>	Input Bias Current	V <sub>CM</sub> = V <sub>S</sub> <sup>-</sup> + 1V	●		30	400	nA
		V <sub>CM</sub> = V <sub>S</sub> <sup>+</sup> - 0.2V	●		450	1750	nA
I <sub>OS</sub>	Input Offset Current	V <sub>CM</sub> = V <sub>S</sub> <sup>-</sup> + 1V	●		25	300	nA
		V <sub>CM</sub> = V <sub>S</sub> <sup>+</sup> - 0.2V	●		25	300	nA
A <sub>VOL</sub>	Large-Signal Voltage Gain	V <sub>O</sub> = -4V to 4V, R <sub>L</sub> = 1k	●	20	55		V/mV
		V <sub>O</sub> = -2V to 2V, R <sub>L</sub> = 100Ω	●	2	5		V/mV
CMRR	Common Mode Rejection Ratio	V <sub>CM</sub> = V <sub>S</sub> <sup>-</sup> to 3.5V	●	82	105		dB
	Input Common Mode Range		●	V <sub>S</sub> <sup>-</sup>		V <sub>S</sub> <sup>+</sup>	V
PSRR	Power Supply Rejection Ratio	V <sub>S</sub> <sup>+</sup> = 2.5V to 10V, V <sub>S</sub> <sup>-</sup> = 0V	●	74	91		dB
V <sub>OL</sub>	Output Voltage Swing Low (Note 7)	No Load	●		17	70	mV
		I <sub>SINK</sub> = 5mA	●		105	210	mV
		I <sub>SINK</sub> = 20mA	●		250	575	mV
V <sub>OH</sub>	Output Voltage Swing High (Note 7)	No Load	●		25	90	mV
		I <sub>SOURCE</sub> = 5mA	●		150	310	mV
		I <sub>SOURCE</sub> = 20mA	●		600	975	mV
I <sub>SC</sub>	Short-Circuit Current		●	25	45		mA
I <sub>S</sub>	Supply Current per Amplifier		●		2.4	3.5	mA
GBW	Gain Bandwidth Product	Frequency = 2MHz	●		70		MHz
SR	Slew Rate	A <sub>V</sub> = -1, R <sub>L</sub> = 1k, V <sub>O</sub> = ±4V, Measured at V <sub>O</sub> = ±2V	●		20		V/μs

**ELECTRICAL CHARACTERISTICS** The ● denotes the specifications which apply over the temperature range of  $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ .  $V_S = \pm 5\text{V}$ ,  $V_{\text{CM}} = 0\text{V}$ ,  $V_{\text{OUT}} = 0\text{V}$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
$V_{\text{OS}}$	Input Offset Voltage	$V_{\text{CM}} = V_{\text{S}}^{-}$	●		350	900	$\mu\text{V}$
		$V_{\text{CM}} = V_{\text{S}}^{-}$ (SOT-23)	●		500	2250	$\mu\text{V}$
		$V_{\text{CM}} = V_{\text{S}}^{+}$	●		0.75	4.5	mV
		$V_{\text{CM}} = V_{\text{S}}^{+}$ (SOT-23)	●		1	5.5	mV
$\Delta V_{\text{OS}}$	Input Offset Shift	$V_{\text{CM}} = V_{\text{S}}^{-}$ to $V_{\text{S}}^{+} - 1.5\text{V}$	●		50	750	$\mu\text{V}$
$V_{\text{OS TC}}$	Input Offset Voltage Drift (Note 8)	$V_{\text{CM}} = V_{\text{S}}^{-}$	●		1.5		$\mu\text{V}/^{\circ}\text{C}$
		$V_{\text{CM}} = V_{\text{S}}^{+}$	●		1.5		$\mu\text{V}/^{\circ}\text{C}$
$I_{\text{B}}$	Input Bias Current	$V_{\text{CM}} = V_{\text{S}}^{-} + 1\text{V}$	●		50	450	nA
		$V_{\text{CM}} = V_{\text{S}}^{+} - 0.2\text{V}$	●		450	2000	nA
$I_{\text{OS}}$	Input Offset Current	$V_{\text{CM}} = V_{\text{S}}^{-} + 1\text{V}$	●		25	350	nA
		$V_{\text{CM}} = V_{\text{S}}^{+} - 0.2\text{V}$	●		25	350	nA
$A_{\text{VOL}}$	Large-Signal Voltage Gain	$V_{\text{O}} = -4\text{V}$ to $4\text{V}$ , $R_{\text{L}} = 1\text{k}$	●	16	55		V/mV
		$V_{\text{O}} = -1\text{V}$ to $1\text{V}$ , $R_{\text{L}} = 100\Omega$	●	2	5		V/mV
CMRR	Common Mode Rejection Ratio	$V_{\text{CM}} = V_{\text{S}}^{-}$ to $3.5\text{V}$	●	81	104		dB
	Input Common Mode Range		●	$V_{\text{S}}^{-}$		$V_{\text{S}}^{+}$	V
PSRR	Power Supply Rejection Ratio	$V_{\text{S}}^{+} = 2.5\text{V}$ to $10\text{V}$ , $V_{\text{S}}^{-} = 0\text{V}$	●	73	90		dB
$V_{\text{OL}}$	Output Voltage Swing Low (Note 7)	No Load	●		15	80	mV
		$I_{\text{SINK}} = 5\text{mA}$	●		105	220	mV
		$I_{\text{SINK}} = 10\text{mA}$	●		170	400	mV
$V_{\text{OH}}$	Output Voltage Swing High (Note 7)	No Load	●		25	100	mV
		$I_{\text{SOURCE}} = 5\text{mA}$	●		150	350	mV
		$I_{\text{SOURCE}} = 10\text{mA}$	●		300	700	mV
$I_{\text{SC}}$	Short-Circuit Current		●	12.5	30		mA
$I_{\text{S}}$	Supply Current per Amplifier		●		2.6	4	mA
GBW	Gain Bandwidth Product	Frequency = $2\text{MHz}$	●		65		MHz
SR	Slew Rate	$A_{\text{V}} = -1$ , $R_{\text{L}} = 1\text{k}$ , $V_{\text{O}} = \pm 4\text{V}$ , Measured at $V_{\text{O}} = \pm 2\text{V}$	●		15		V/ $\mu\text{s}$

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of the device may be impaired.

**Note 2:** The inputs are protected by back-to-back diodes and by ESD diodes to the supply rails. If the differential input voltage exceeds 1.4V or either input goes outside the rails, the input current should be limited to less than 10mA.

**Note 3:** A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely.

**Note 4:** The LT1800/LT1800I are guaranteed functional over the temperature range of  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

**Note 5:** The LT1800C is guaranteed to meet specified performance from  $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$ . The LT1800C is designed, characterized and expected to meet specified performance from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  but is not tested or QA sampled at these temperatures. The LT1800I is guaranteed to meet specified performance from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

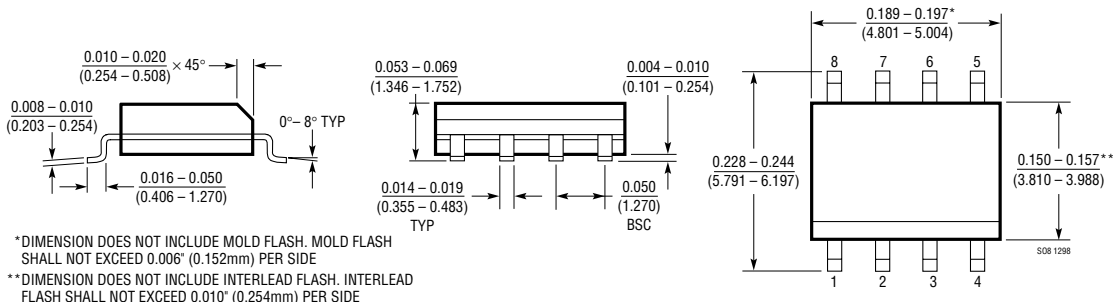
**Note 6:** Minimum supply voltage is guaranteed by power supply rejection ratio test.

**Note 7:** Output voltage swings are measured between the output and power supply rails.

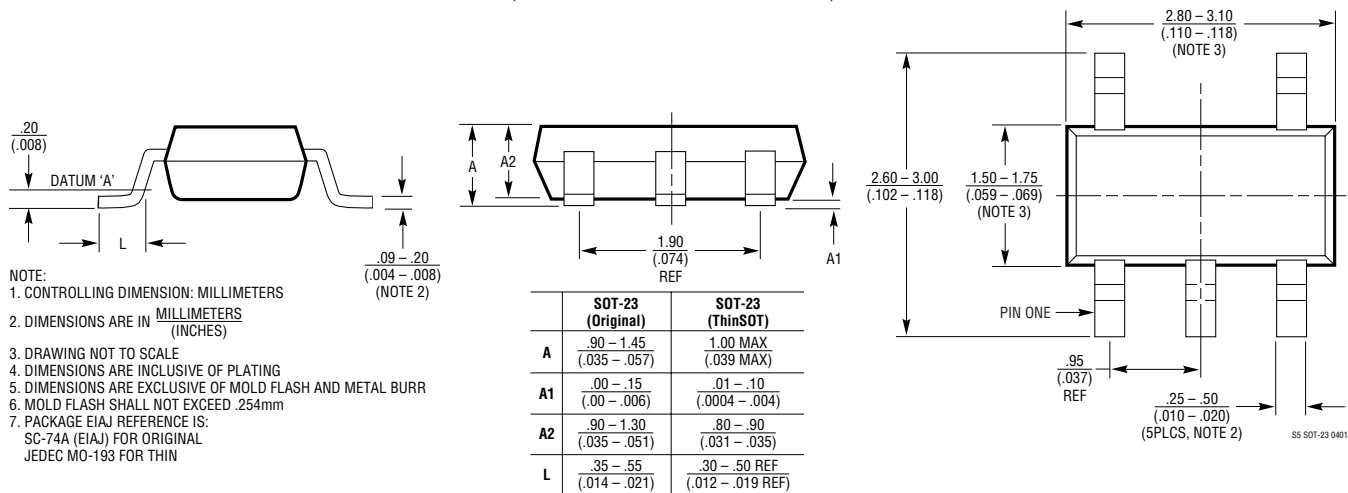
**Note 8:** This parameter is not 100% tested.

# PACKAGE DESCRIPTION

## S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



## S5 Package 5-Lead Plastic SOT-23 (Reference LTC DWG # 05-08-1633) (Reference LTC DWG # 05-08-1635)



## RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1498/LT1499	Dual/Quad 10MHz, 6V $\mu$ s Rail-to-Rail Input and Output C-Load™ Op Amps	High DC Accuracy, 475 $\mu$ V V <sub>OS(MAX)</sub> , 4 $\mu$ V/°C Max Drift, Max Supply Current 2.2mA per Amp
LT1630/LT1631	Dual/Quad 30MHz, 10V/ $\mu$ s Rail-to-Rail Input and Output Op Amps	High DC Accuracy, 525 $\mu$ V V <sub>OS(MAX)</sub> , 70mA Output Current, Max Supply Current 4.4mA per Amplifier
LT1806/LT1807	Single/Dual 325MHz, 140V/ $\mu$ s Rail-to-Rail Input and Output Op Amps	High DC Accuracy, 550 $\mu$ V V <sub>OS(MAX)</sub> , Low Noise 3.5nV/ $\sqrt$ Hz, Low Distortion -80dB at 5MHz

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